# Gain Stabilization of SiPMs

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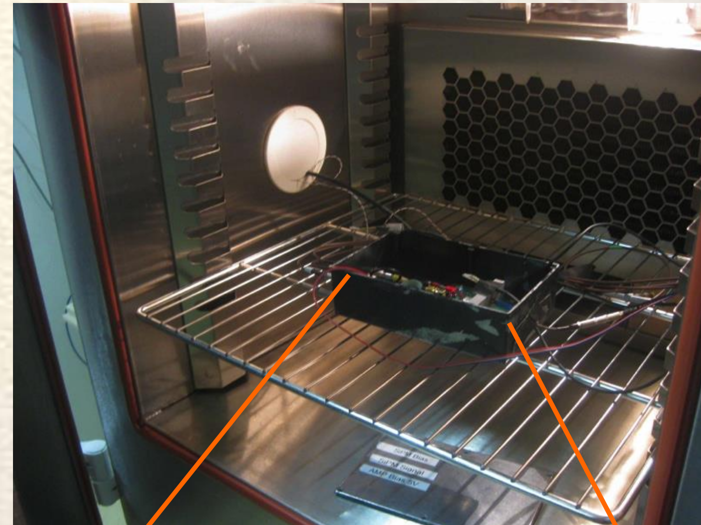
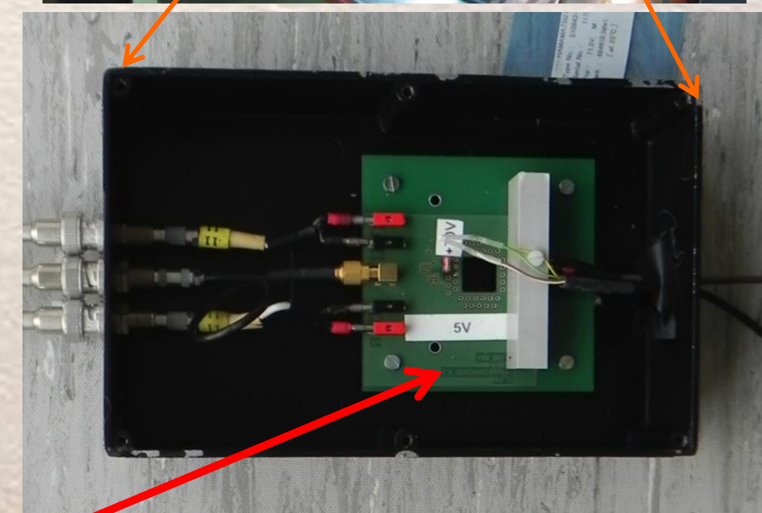
# Introduction

- The gain of SiPMs depends both on bias voltage and on temperature
  - Gain decreases with temperature
  - Gain increases with bias voltage
- For stable operations, we need to keep gain constant
- In an analogue hadron calorimeter with millions of channels, this is a difficult task due to temperature variations
- Thus, it is desirable to adjust $\mathbf{V_{bias}}$ to compensate for **T** changes to keep the gain constant
- Goal: build a $V_{bias}$ regulator to keep gain constant (<1%)
- First, we need to measure SiPM gain vs temperature and vs $V_{bias}$
  ➔ determine dV/dT to obtain constant gain
  ➔ apply the compensation and demonstrate proof of principle
- This is work conducted in the framework of the EU project AIDA

# SiPM Test Setup

- We work in a climate chamber at CERN that is stable within 0.2°C
- Use digital oscilloscope read out by PC, low voltage & bias voltage power supplies
- Use pulse generator for LED signal
- Blue LED shines on SiPM

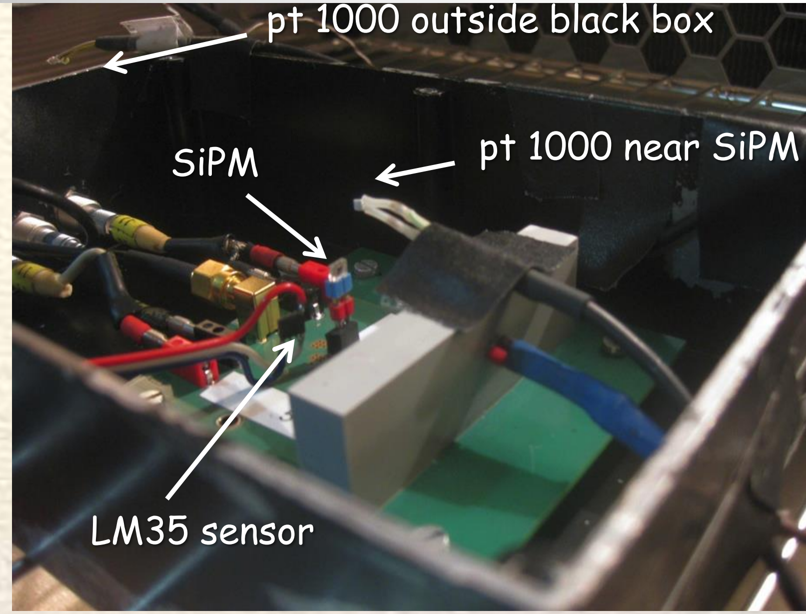



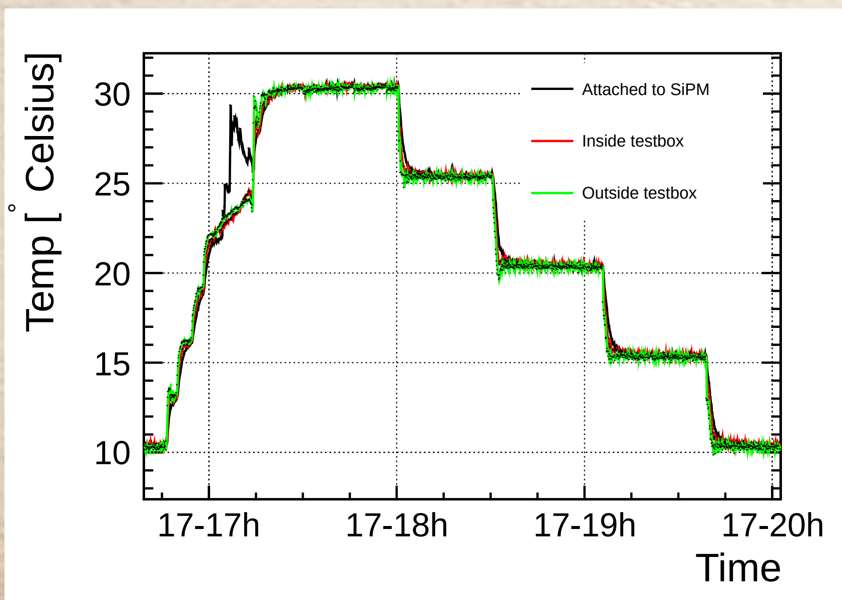


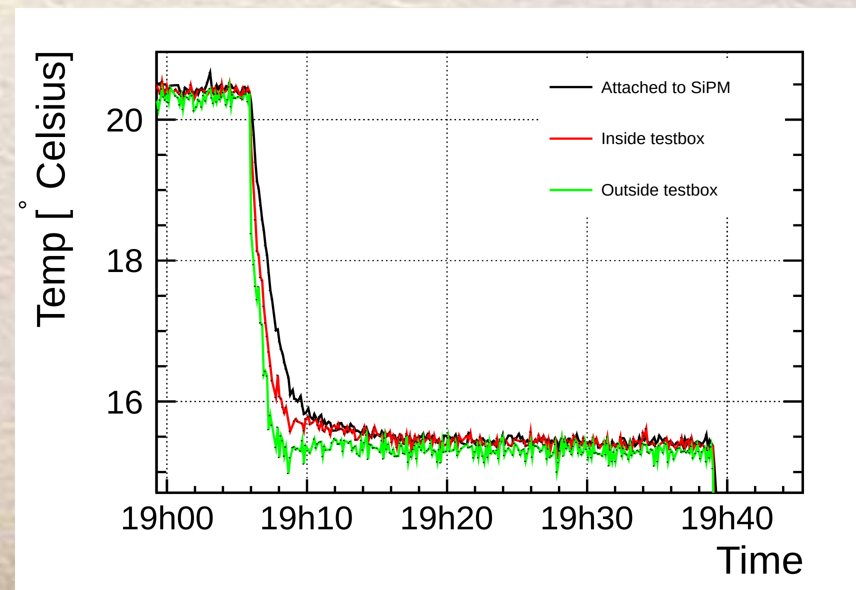

SiPM + preamp +T sensor + LED

# Temperature Measurement

- Use 3 pt 1000 sensors
  - Near SiPM, inside and outside black box
- Use LM35 sensor for compensation feedback
- Vary T from 5°C to 40°C in 5°C steps except in 20°- 30°C range (2°C steps)
  - ➔ $T_{SiPM} \sim T_{SET} + 0.4°C$,
  - ➔ offset is same over entire range



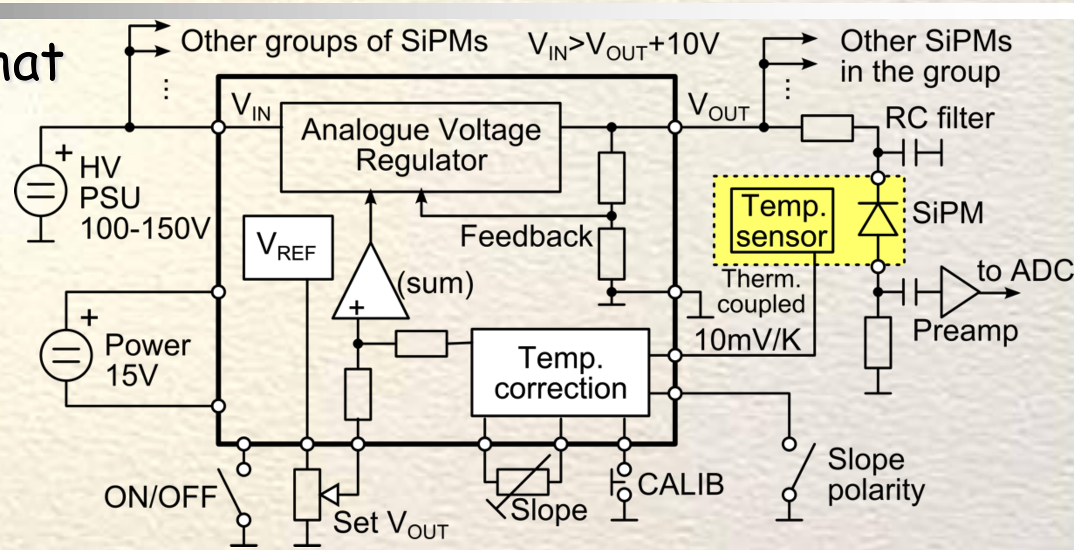
# SiPM Tested

- We measured the dG/dT & dG/dV dependence for 15 SiPMs from 3 manufacturers
- We tested the $V_{bias}$ adjustment on 4 SiPMs:
  - CPTA 857
  - CPTA 1677
  - KETEK W 12
  - MPPC 50um 11759
  - MPPC 20um "B"
- Note that CPTA sensors were attached to 3x3 $cm^2$ scintillator tiles while the other sensors were directly illuminated by blue LED

| Manufacturer and Type # | Sensitive area $[mm^2]$ | Pixel pitch $[\mu m]$ | #pixels | Typical $V_{bias}$ [V] | Typical $G$ $[\times 10^5]$ | Serial # |
|---|---|---|---|---|---|---|
| Hamamatsu | | | | | | |
| → S10943-8584(X) | $1\times1$ | 50 | 400 | 71.69 | 7.49 | 11759 |
| S10943-8584(X) | $1\times1$ | 50 | 400 | 71.57 | 7.49 | 11766 |
| S10943-8584(X) | $1\times1$ | 50 | 400 | 71.50 | 7.48 | 11770 |
| S10943-8584(X) | $1\times1$ | 50 | 400 | 71.33 | 7.48 | 11771 |
| Sample A | $1\times1$ | 20 | 2500 | 66.7 | 2.3 | A1 |
| Sample B | $1\times1$ | 20 | 2500 | 73.3 | 2.3 | B1 |
| Sample A | $1\times1$ | 15 | 4440 | 67.2 | 2.0 | A2 |
| Sample B | $1\times1$ | 15 | 4440 | 74.0 | 2.0 | B2 |
| CPTA | | | | | | |
| → | $1\times1$ | 40 | 796 | 33.4 | 7.1 | 857 |
| | $1\times1$ | 40 | 796 | 33.1 | 6.3 | 922 |
| | $1\times1$ | 40 | 796 | 33.3 | 6.3 | 975 |
| | $1\times1$ | 40 | 796 | 33.1 | 7.0 | 1065 |
| → | $1\times1$ | 40 | 796 | 33.3 | 14.6 | 1677 |
| KETEK | | | | | | |
| MP15 V6 ? | $2(1.2\times1.2)$ | 15? | ? | −28 | ? | W8 |
| → MP20 V4 ? | $3\times3$ | 20? | ? | −28 | ? | W12 |

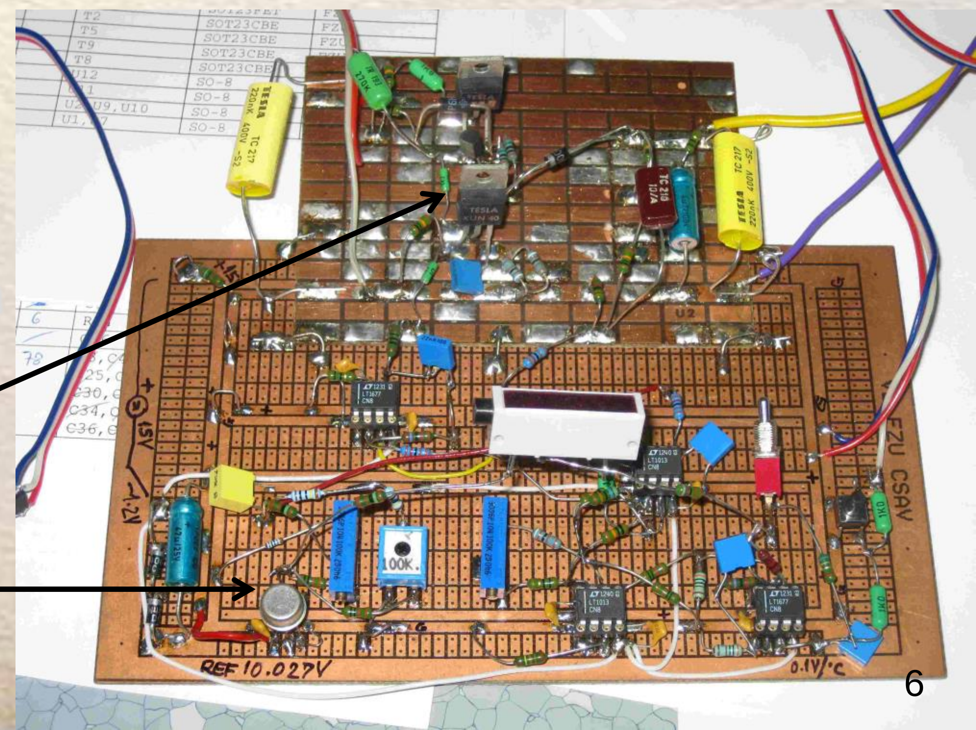
# Layout of the Adaptive Power Regulator

- Ivo designed $V_{bias}$ regulator that operates in 10 V to 80 V region plus T correction effects
- Temperature slope: <1 to100 mV/K, both positive and negative
- First design of test board done summer 2013
- Tested in CERN Sep 2013, results shown in this presentation



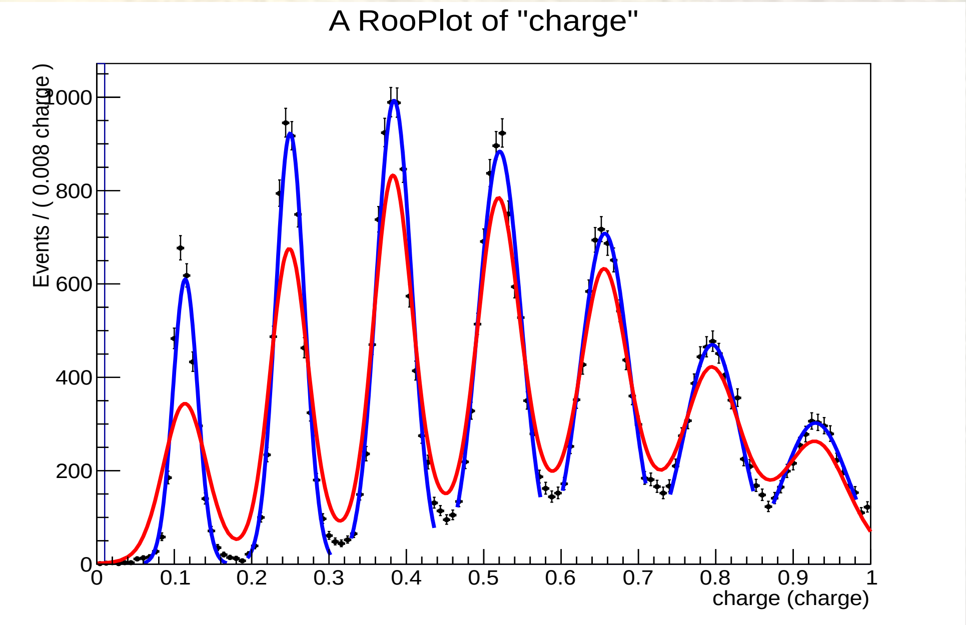

Analogue voltage regulator

Voltage reference



# Gain Determination (being updated)

- Determine gain by fitting Gaussian functions to peaks of single pe spectra
- Define gain as
  - Distance between 1 pe & 2 pe peaks (MPPCs)
  - Distance between pedestal & 1 pe peak (CPTA, KETEK)



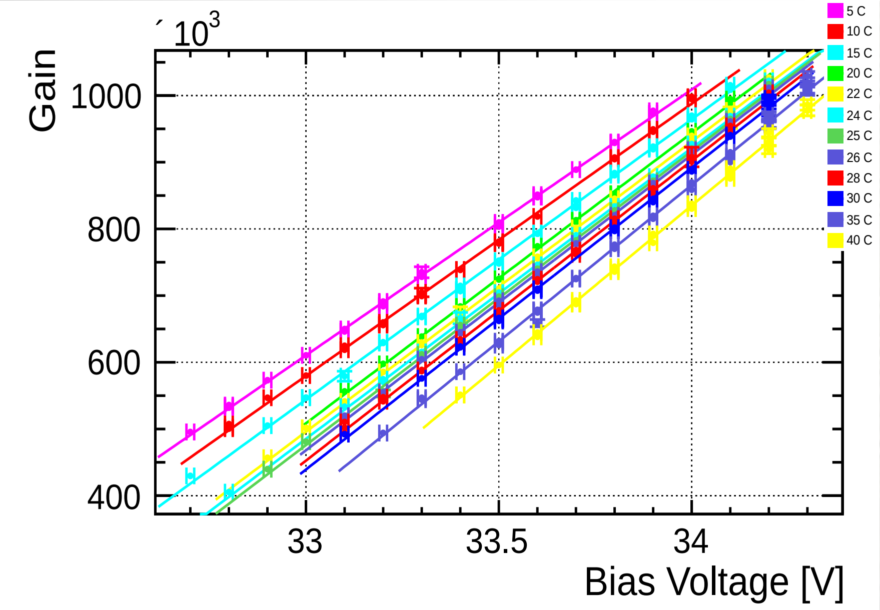

RooFit multikernel function
Individual Gaussian fits

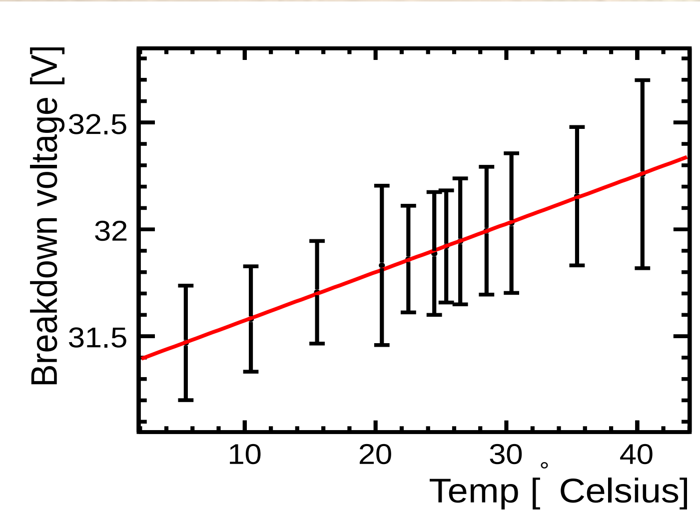
- Define the error on the gain as the errors of the two fitted Gaussian mean values added in quadrature

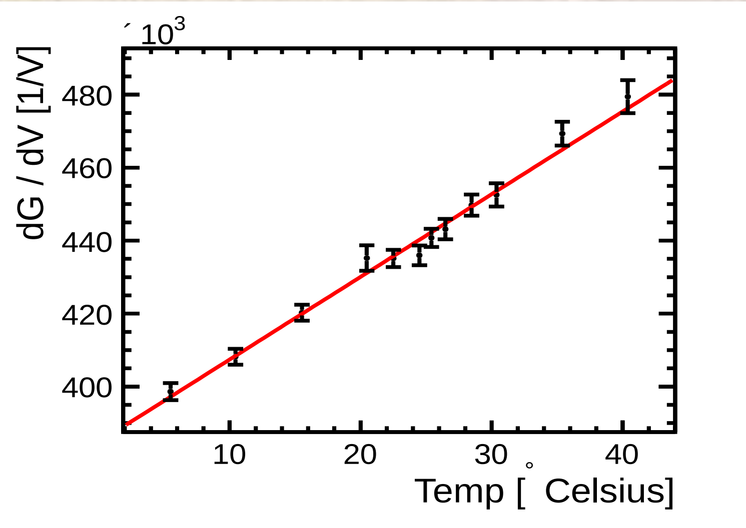
- Quality cut: Require gain extracted from Gaussian peaks and that from multikernel peaks not to differ by more than 20% (a sign of a bad fit)

# Gain vs Voltage for CPTA 857

- Each point is the gain extracted from 50k waveforms of 80 ns
- Linear fit to these distributions yields break-down voltage & dG/dV
- Break-down voltage drops with T
- dG/dV~ capacitance is not constant
  ➔ it increases linearly with temperature

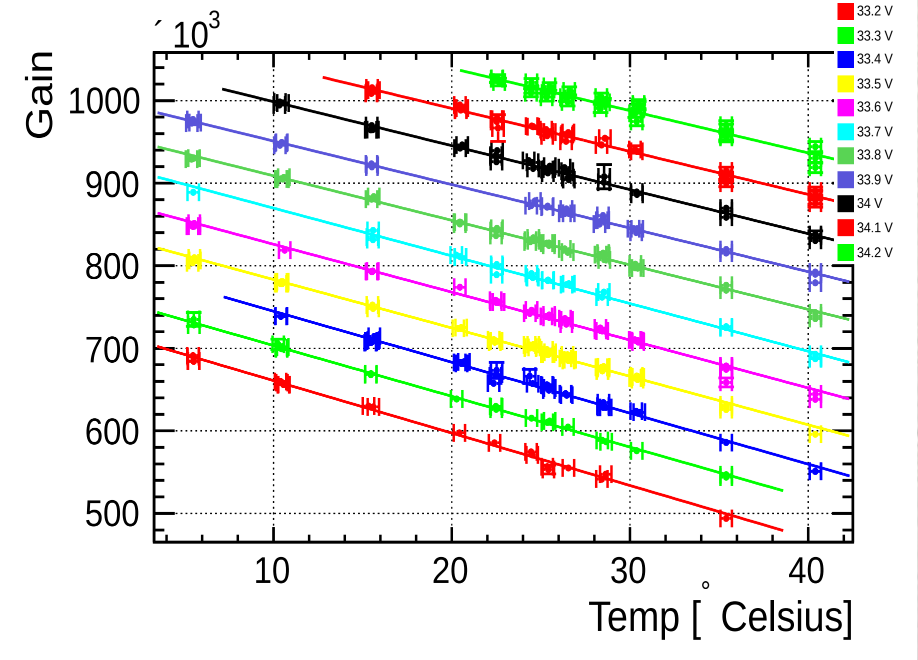


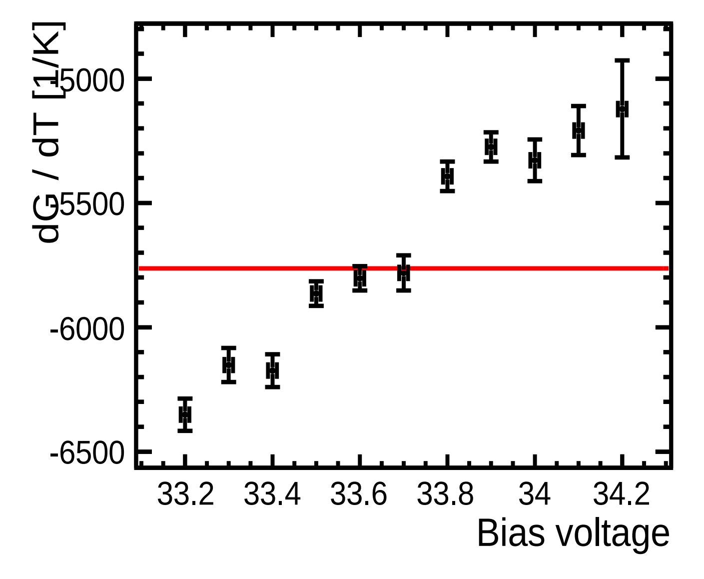



# Gain vs Temperature for CPTA 857

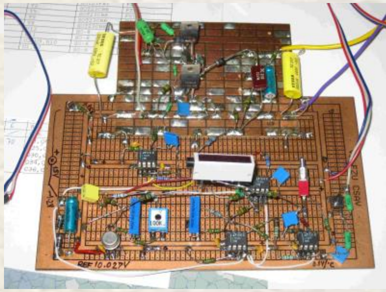
- At $V_{bias}$=33.4 V & T=25°C:
  $G=6.4\times10^5$
- Extract $V_{breakdown}$=31.9 V
- $0^{th}$ order polynomial fit yields:
  $dG/dV=(4.32\pm0.01_{stat})\times10^5/K$
- $1^{st}$ order polynomial fit yields:
  $dG/dV=(4.41\pm0.11_{sys})\times10^5/K$



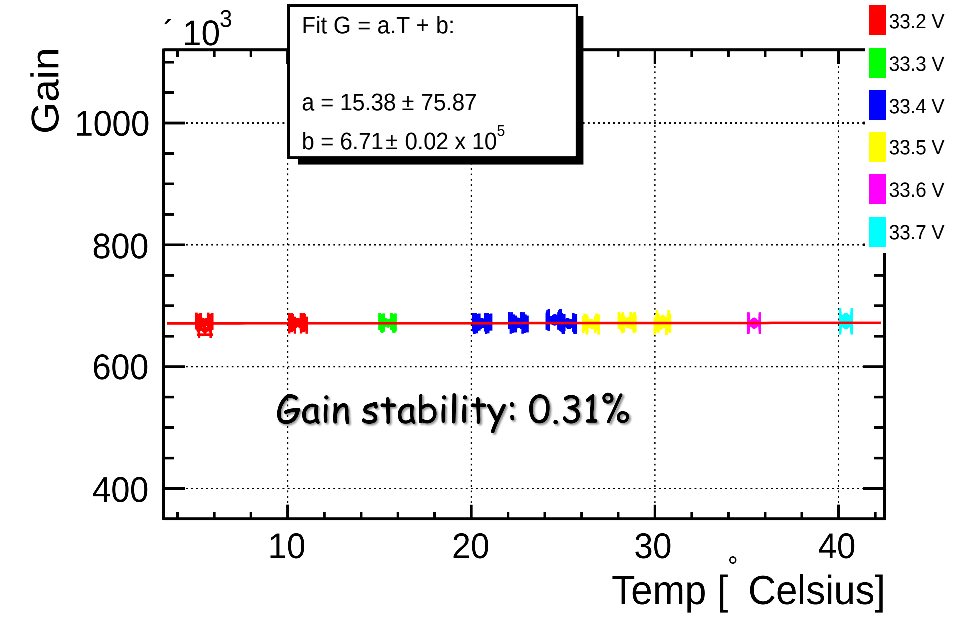

- $0^{th}$ order polynomial fit yields:
  $dG/dT=(-5.76\pm0.02_{stat})\times10^3/K$
- Determine:
  $dV/dT=\langle dG/dT\rangle/\langle dG/dV\rangle$
  $= 13.33\oplus0.35$ mV/K
- Gain stability:
  $\sigma(dV/dT)\cdot(dG/dV)\cdot(\Delta T/G)$
  = 0.31%

# Gain after $V_{bias}$ Adjustment for CPTA 857



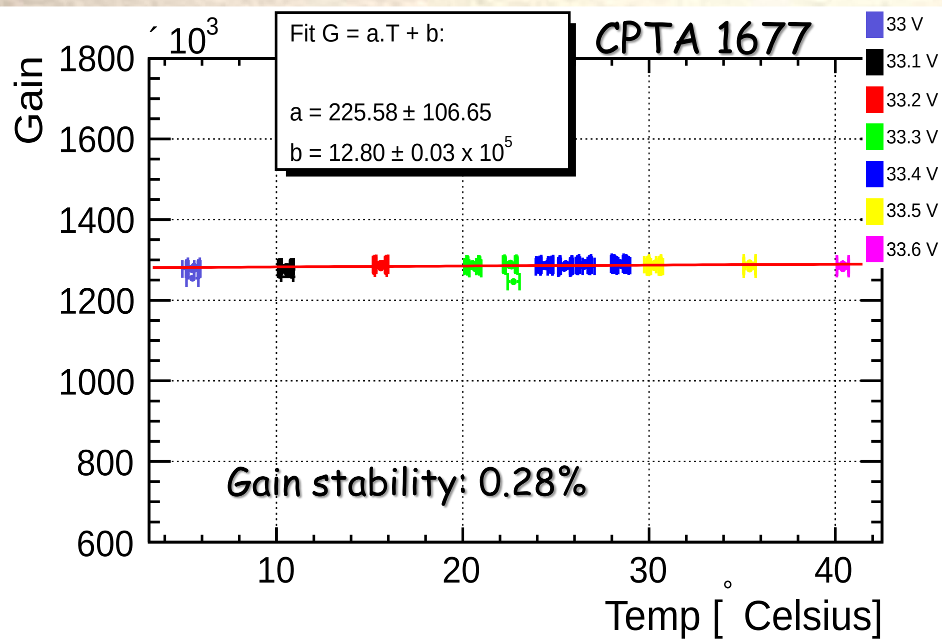
- Adjust voltage using $V_{bias}$ regulator test board (Note: color code gives the range of voltage applied e.g. blue: $33.35 < V_{bias} < 33.45$)
- At each temperature, take 20 samples with 50k waveform each
- Linear fit to all data points
  - offset: $(6.71 \pm 0.02) \times 10^5$
  - slope: $15.38 \pm 75.87$
- Gain is uniform in range of interest 5°- 40°C
  ➔ measured non-uniformity is < ±0.04%

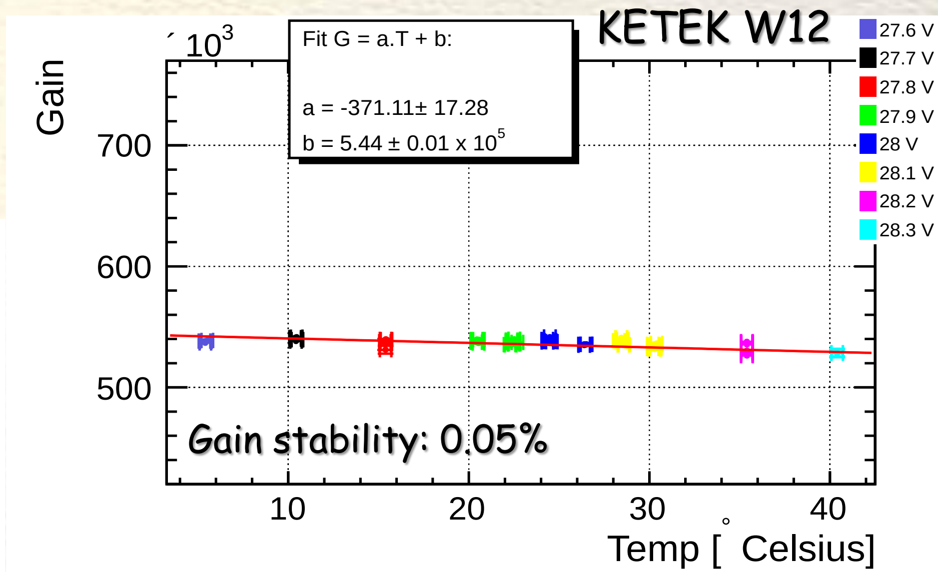
CPTA 857

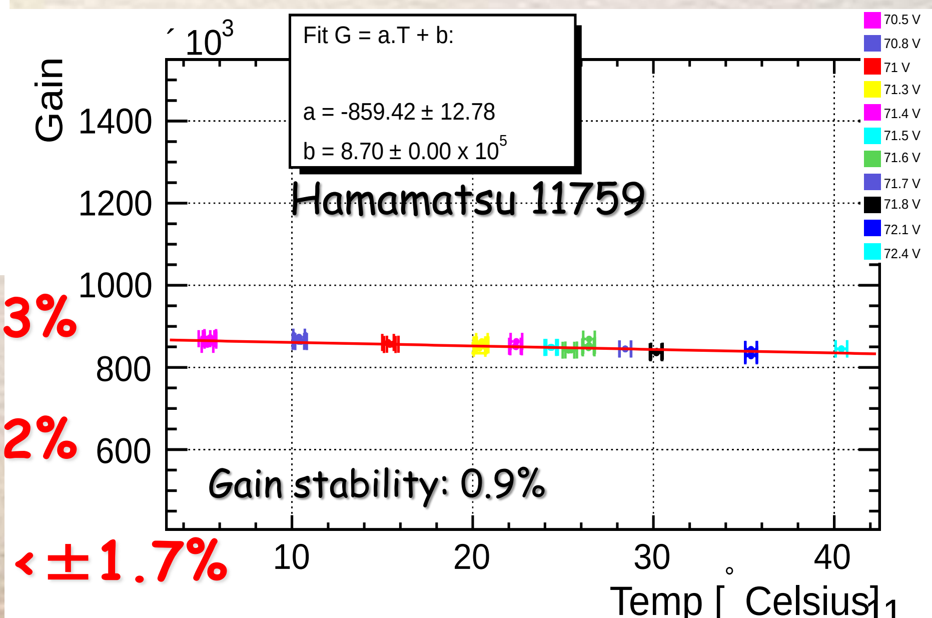


# Gain after $V_{bias}$ Adjustment for other SiPMs

- Perform similar study with 3 other SiPMs from CPTA, KETEK and Hamamatsu



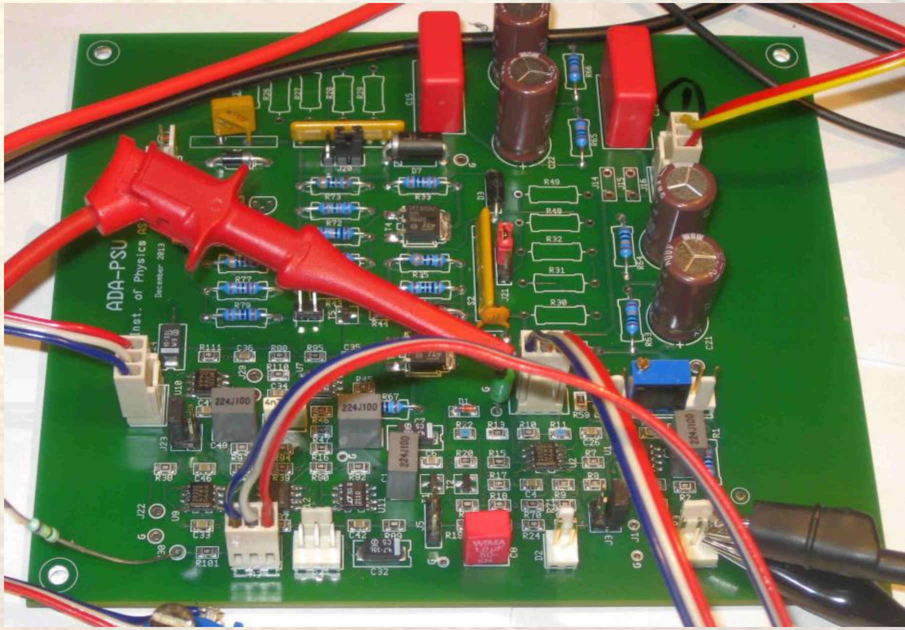

- CPTA 1677: non-uniformity < ± 0.3%
- KETEK W12: non-uniformity < ±1.2%
- Hamamatsu 11759: non-uniformity < ±1.7%

# Summary of the 2013 measurements

- Results from the measurements @ CERN 2013:
  - 4 SiPM measured and compensated
    - T range 5° – 40°C
    - Large statistics taken, dG/dV, dG/dT calculated
    - dV/dT extrapolated ➔ used as a compensation constant
    - Measurement taken with the Adaptive $V_{bias}$ adjustment test board
  - Various dV/dT:
    - 15-20 mV/K for CPTA & KETEK sensors
    - 55 mV/K for Hamamatsu sensors
  - Hamamatsu sensors operate at higher $V_{bias}$ than CPTA/KETEK sensors
  - Adjustment range ΔV=0.7 (1.9) V for CPTA & KETEK (Hamamatsu) for
- The gain stabilization with the $V_{bias}$ regulator test board works well ➔for all four tested SiPMs, gain stability is < 1% as required

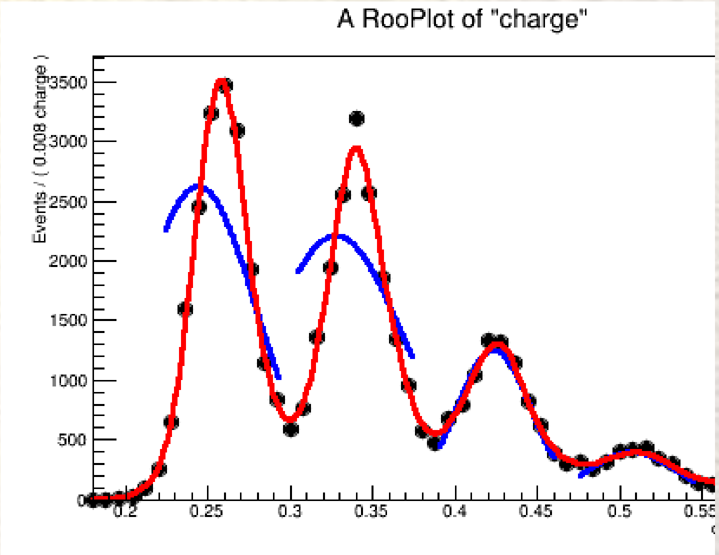
# Adaptive Power Regulator 2nd Prototype

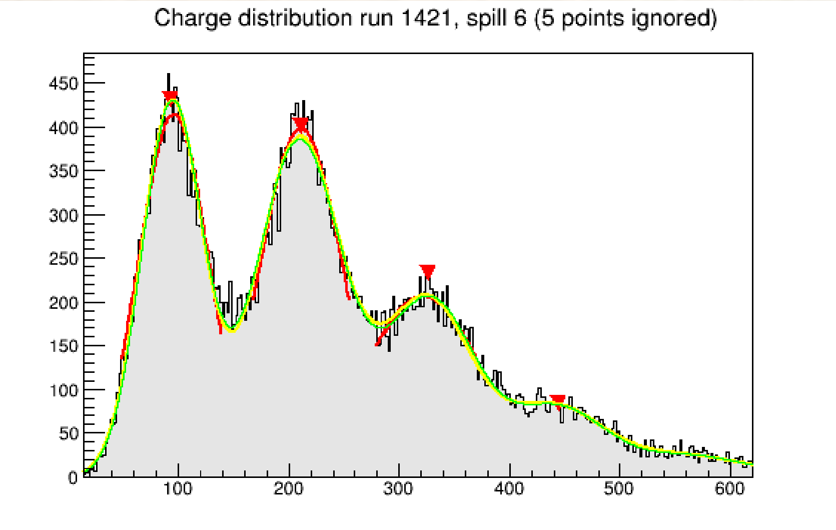
- Prototype finished in Jan 2014
  - Extended V range:
    - SiPM <130 V
    - APD <450V
  - Has a front panel
- Delivered to CERN in Feb 2014
  - 5 SiPMs measured, same setup
  - T range extended: 1~50˚C
  - Data analysis ongoing

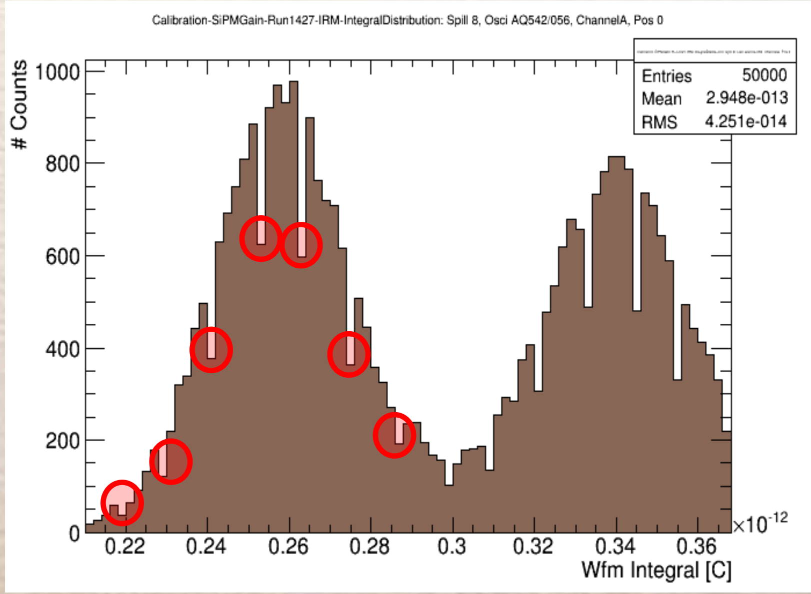



# Analysis (being updated)

- Some bad fits observed in the data ➔ loosing statistics ➔ we want to improve that
  - Problem observed in the histogram
  - Cause: Numerical rounding issue?
- Charge extraction procedure rewritten
- Ongoing evaluation of best fit option
  - Individual peak fits
  - RootKeysPDF
  - Sum of Gaussians (deals better with noisy histograms from high T)



# Summary (2014) and Next Steps

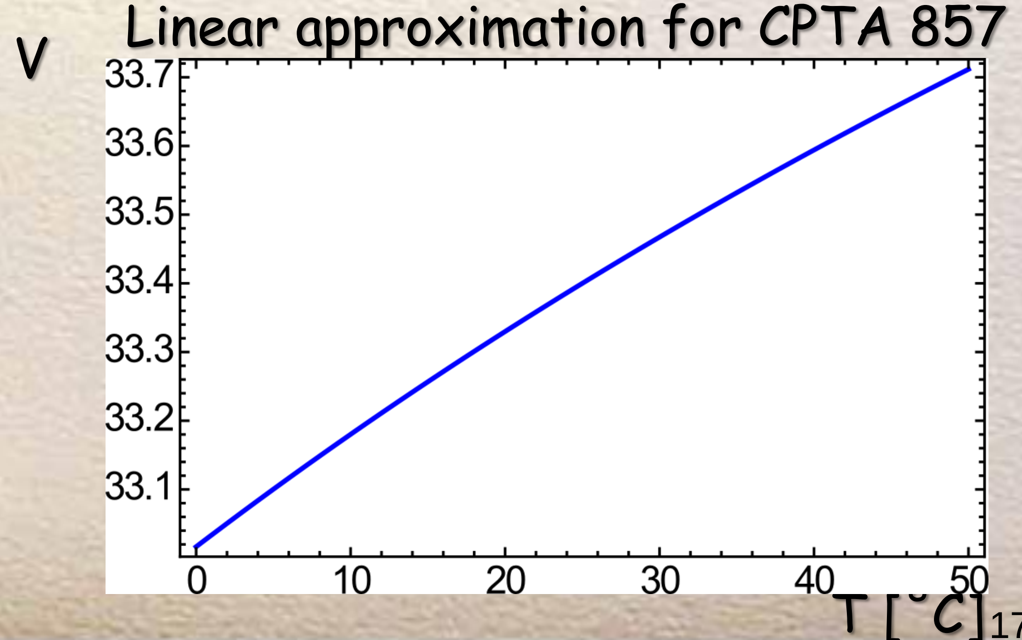
- ADApower prototype finished Jan 2014
- New data was taken @ CERN Feb 2014 and will be analyzed →
  - Aim for better gain extraction
  - Check the previous (2013) data
- AIDA note almost finished (delayed), will be released soon
- Q2 2014 assemble and finalize few other units of ADApower box
- Integrate the $V_{bias}$ regulator PCB into the FE readout electronics of the AHCAL → summer 2014
- Write final report for AIDA project → fall 2014

# Backup Slides

# Voltage Temperature Relation

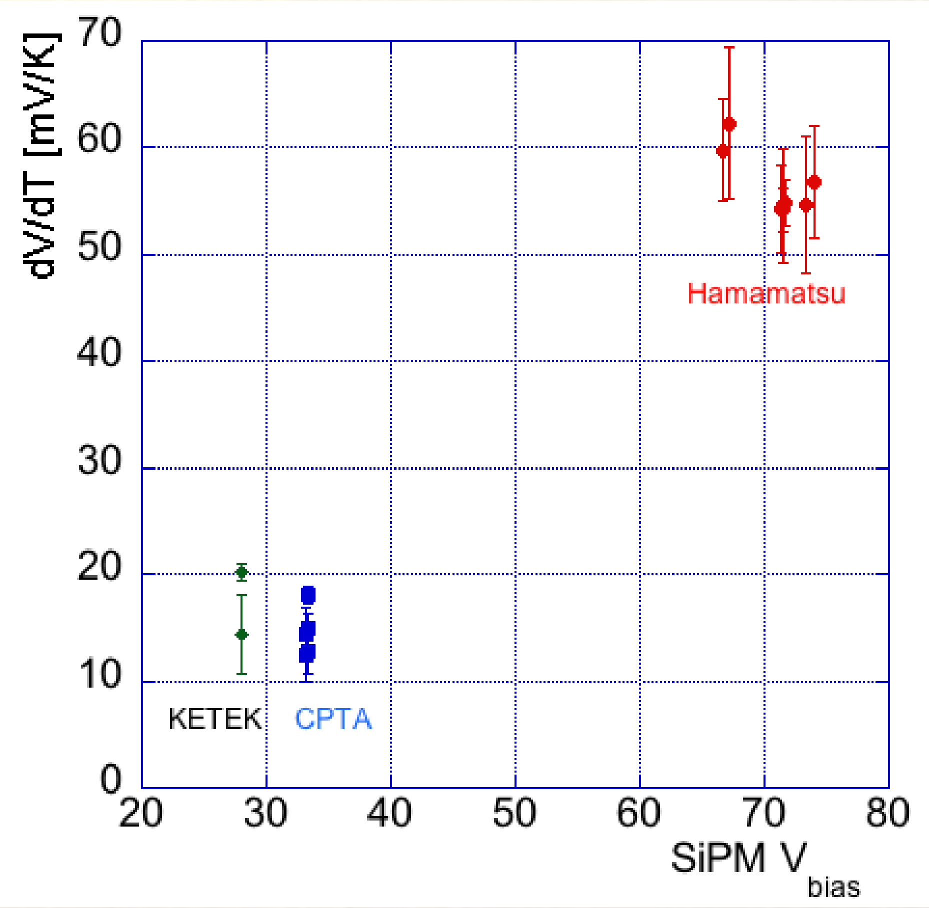
- dV/dT is obtained from a ratio of 2 first-order differential equations
  - **dG/dT=a-b*V**+O(V²)
  - **dG/dV=c+d*T**+O(T²)
- Thus, an analytical solution exists
  - For the above linear case, we get: $V[T] = \frac{a}{b} + (c + d \cdot T)^{\frac{-b}{d}} \cdot C$ (d≠0)
- For a linear model in dG/dT and dG/dV find following V versus T dependence

Linear approximation for CPTA 857



# Summary of dV/dT Measurements

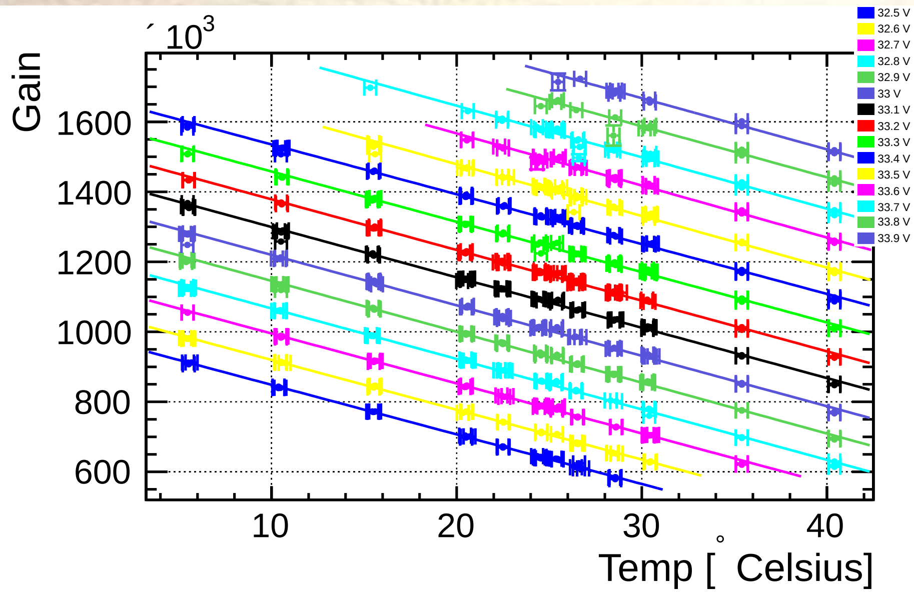
- $V_{bias}$ for Hamamatsu is ~70 V while $V_{bias}$ for CPTA is ~33 V & $V_{bias}$ for KETEK is ~28 V
- For KETEK and CPTA, dV/dT is ~15-20 mV/K for Hamamatsu, dV/dT is ~55 mV/K
- Thus, compensation will be simpler for CPTA and KETEK SiPMs

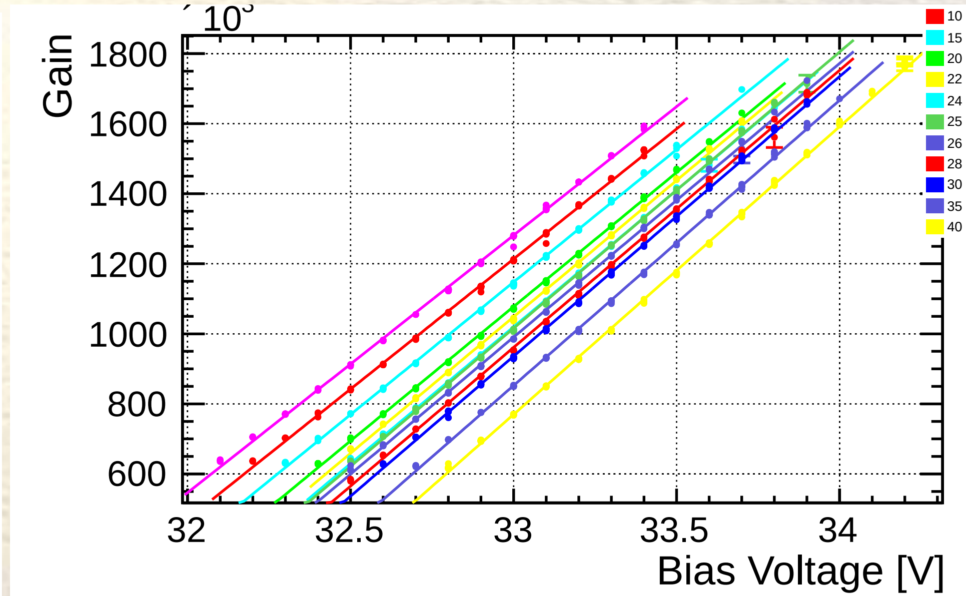


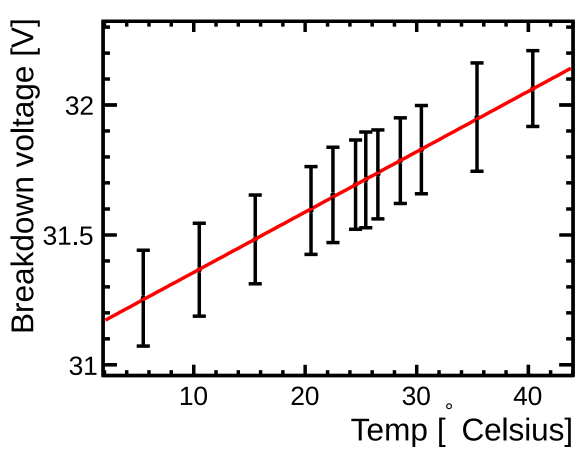

- We tested the compensation on:
  - 4 SiPMs in 2013
  - The same 4 and 1 additional SiPMs in 2014

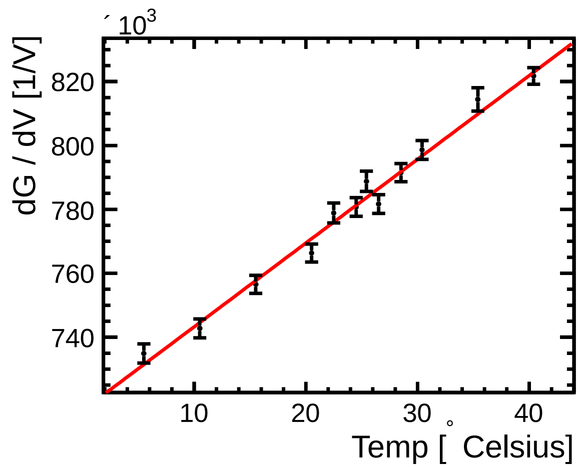
# Results for CPTA 1677

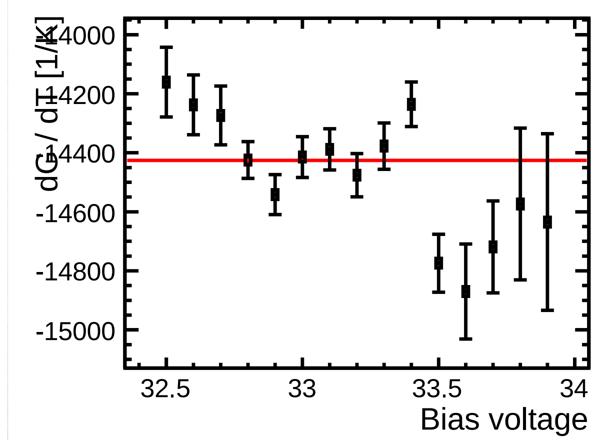
- Extract dV/dT=18.51±0.31 mV/K and gain stability of 0.1%



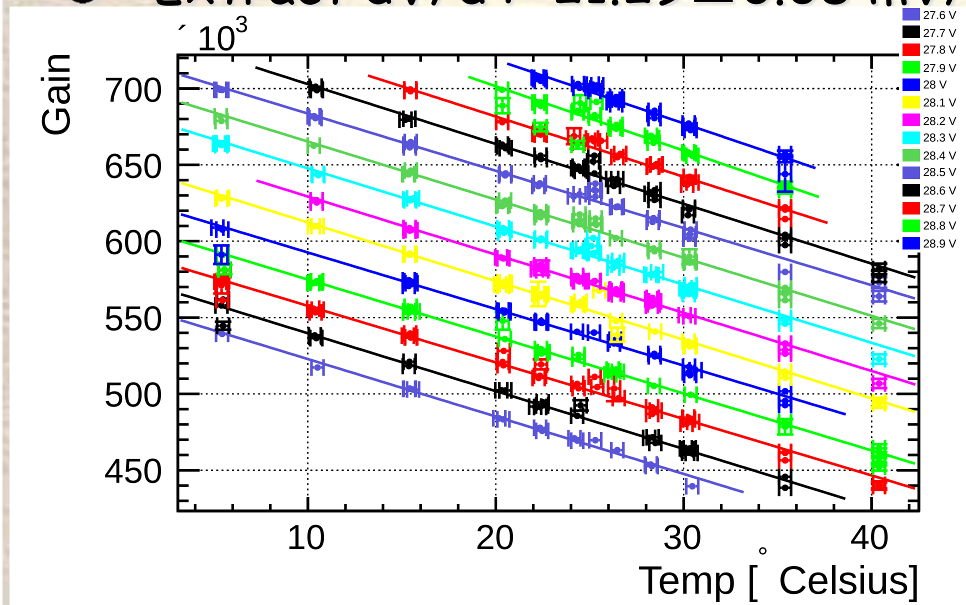



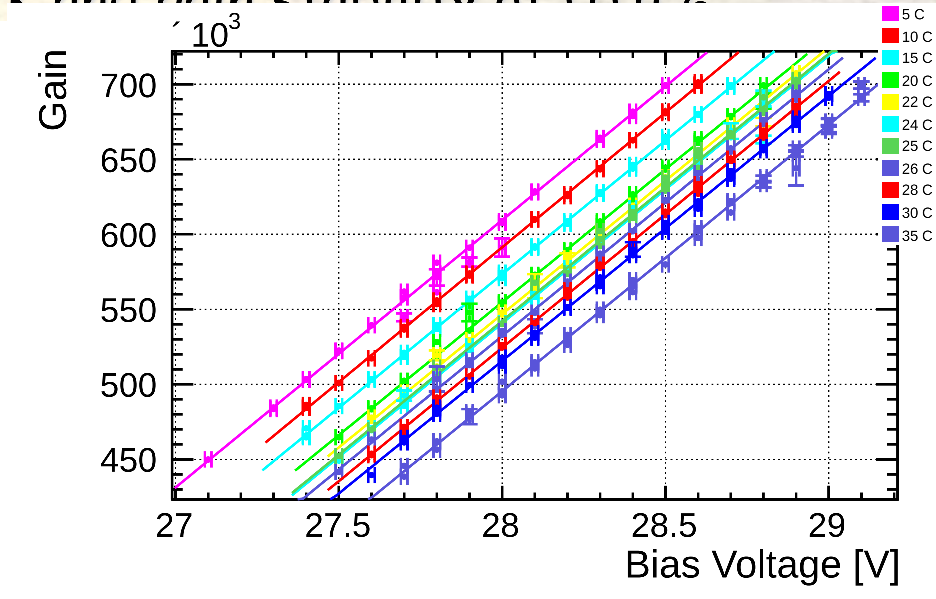



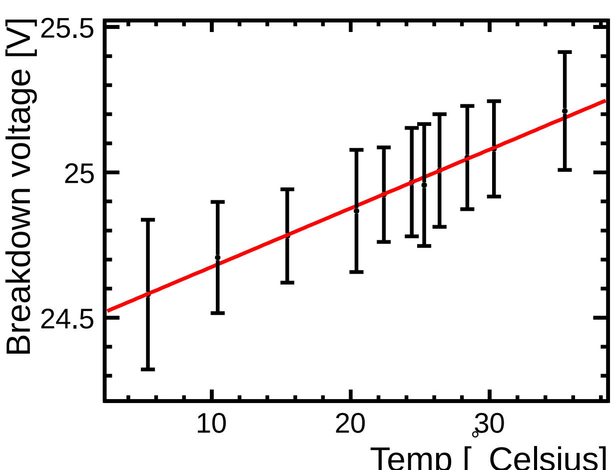



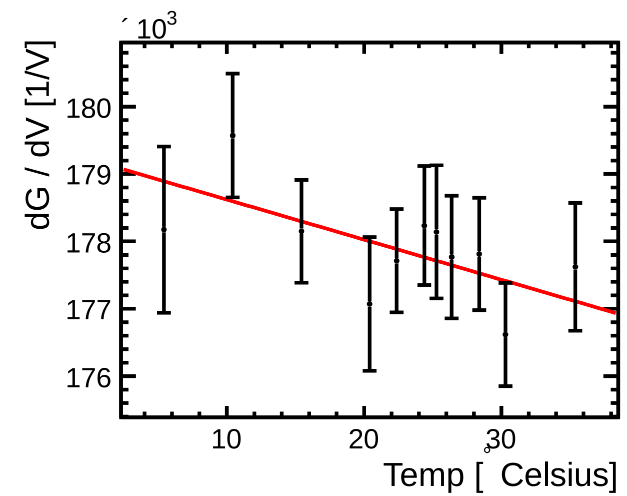
# Results for KETEK W12

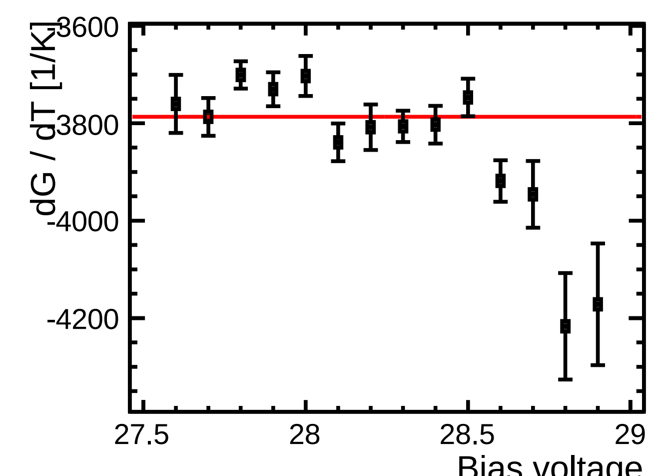
- Extract dV/dT=21.29±0.08 mV/K and gain stability of 0.01%



# Results for Hamamatsu

- Extract dV/dT=54.3±0.75 mV/K and gain stability of 0.28%